AREA SENSORS

LIGHT CURTAINS / SAFETY COMPONENTS PRESSURE / FLOW SENSORS INDUCTIVE PROXIMITY

SENSORS PARTICULAR USE SENSORS

SENSOR OPTIONS

SIMPLE WIRE-SAVING UNITS

WIRE-SAVING SYSTEMS

MEASUREMENT SENSORS STATIC ELECTRICITY PREVENTION

DEVICES LASER MARKERS

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HUMAN MACHINE INTERFACES

ENERGY CONSUMPTION VISUALIZATION COMPONENTS

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UV CURING SYSTEMS

Selection Guide Amplifier Built-in Power Supply Built-in Amplifierseparated

> CX-400 CY-100

> > EX-10

EX-20

EX-40 CX-440

EQ-30 EQ-500

MQ-W

RX-LS200 RX

RX RT-610

ENVIRONMENTAL RESISTANCE

Incorporated an inverter countermeasure circuit*

The **EX-30** series become significantly stronger against inverter light and other extraneous light.

*Effective from production in April 2011.





FUNCTIONS

Bright 2-color indicator

A bright 2-color indicator is incorporated in all types.



No protective tube needed

The **EX-30** series has high bending strength, so that the protective tube used to protect conventional fiber from breakage is not needed. This also adds up to excellent cost performance.



OPERABILITY

Incorporates a sensitivity adjuster (Excluding EX-31)

The sensor incorporates a sensitivity adjuster. It is convenient when you need fine adjustment.

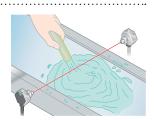


Sensitivity adjuster

Waterproof IP67 (IEC)

The sensor can be hosed down because of its IP67 construction.

Note: However, take care that if it is exposed to water splashes during operation, it may detect a water drop itself.



ORDER GUIDE

Тур	е	Appearance	Sensing range	Model No. (Note)	Output	Output operation
Thru-beam				EX-31A	NPN open-collector	Light-ON
			500 mm 19.685 in	EX-31B	transistor	Dark-ON
				EX-31A-PN	PNP open-collector	Light-ON
F				EX-31B-PN	transistor	Dark-ON
	operation e switch		800 mm 31.496 in	EX-33	NPN open-collector transistor	Switchable
With op mode s	With op mode s			EX-33-PN	PNP open-collector transistor	either Light-ON or Dark-ON
Diffuse reflective				EX-32A	NPN open-collector	Light-ON
		□ 50 mm	EX-32B	transistor	Dark-ON	
			1.969 in	EX-32A-PN	PNP open-collector	Light-ON
Diff				EX-32B-PN	transistor	Dark-ON

Note: The model No. with "P" shown on the label affixed to the thru-beam type sensor is the emitter, "D" shown on the label is the receiver.

5 m 16.404 ft cable length type

5 m 16.404 ft cable length type(standard: 2 m 6.562 ft) is also available for NPN output type [excluding **EX-33(-PN)**]. When ordering this type, suffix "-C5" to the model No.

(e.g.) 5 m 16.404 ft cable length type of **EX-31A** is "**EX-31A-C5**".

OPTIONS

Designation	Model No.	Description		
Slit mask /For thru-beam	OS-EX30-1 (Slit size ø1 mm) ø0.039 in	• Sensing range: 200 mm 7.874 in [EX-31□(-PN)] Slit on one side 320 mm 12.598 in [EX-33(-PN)] • Min. sensing object: Ø2 mm Ø0.079 in		
type sensor only		• Sensing range: 150 mm 5.906 in [EX-31□(-PN)] Slit on both sides 240 mm 9.449 in [EX-33(-PN)] • Min. sensing object: Ø1 mm Ø0.039 in		

Note: One slit and two spacers are provided per set. Two sets are required when installing on both sides.

Slit mask

• OS-EX30-1



Apply the optional slit mask when detecting small objects or for increasing the accuracy of sensing position.

However, the sensing range is reduced when the slit mask is mounted.

SPECIFICATIONS

Туре		Thru-beam With operation mode switch			Diffuse reflective				
	Model No.	NPN output	EX-31A	EX-31B	EX-33	EX-32A	EX-32B		
Item	ı \ M	PNP output	EX-31A-PN	EX-31B-PN	EX-33-PN	EX-32A-PN	EX-32B-PN		
Sen	sing range		500 mm	19.685 in	800 mm 31.496 in	50 mm 1.969 in (Note 2)			
Sen	sing object		ø2 mm ø0.079 in or more	opaque object (Completely	beam interrupted objects)	Opaque, translucent or tra	ansparent object (Note 3)		
Hysteresis						15 % or less of operation distance (Note 2)			
Repeatability (perpendicular to sensing axis)		0.05 mm 0.002 in or less			0.5 mm 0.020 in or less				
Supply voltage		12 to 24 V DC ±10 % Ripple P-P 10 % or less							
Curr	Current consumption		Emitter: 10 mA or less, Receiver: 10 mA or less			13 mA or less			
Output		<npn output="" type=""> NPN open-collector transistor Maximum sink current: 50 mA Applied voltage: 30 V DC or less (between output and 0 V) Residual voltage: 2 V or less (at 50 mA sink current) 1 V or less (at 16 mA sink current)</npn>			<pnp output="" type=""> PNP open-collector transistor • Maximum source current: 50 mA • Applied voltage: 30 V DC or less (between output and +V) • Residual voltage: 2 V or less (at 50 mA source current) 1 V or less (at 16 mA source current)</pnp>				
	Utilization	category			DC-12 o	or DC-13			
	Output op	eration	Light-ON	Dark-ON	Switchable either Light-ON or Dark-ON	Light-ON	Dark-ON		
	Short-circuit protection		Incorporated						
Res	ponse time		0.5 ms or less						
Operation indicator		Orange LED (lights up when the output is ON) (incorporated on the receiver for thru-beam type)							
Stability indicator			Green LED (lights up under stable light received condition or stable dark condition, incorporated on the receiver)			Green LED (lights up under stable light received condition or stable dark condition)			
Sen	Sensitivity adjuster		Continuously variable adjuster				ıster		
	Pollution degree		3 (Industrial environment)						
4)	Protection		IP67 (IEC)						
ance	Ambient to	emperature	-25 to +55 °C −13 to +131 °F (No dew condensation or icing allowed), Storage: -30 to +70 °C −22 to +158 °F						
sist	Ambient h	umidity	35 to 85 % RH, Storage: 35 to 85 % RH						
talre	Ambient il	luminance	Incandescent light: 3,000 fx at the light-receiving face						
men	EMC		EN 60947-5-2						
iron	Ambient temperature Ambient humidity Ambient illuminance EMC Voltage withstandability Insulation resistance		1,000 V AC for one min. between all supply terminals connected together and enclosure						
Insulation resistance		20 MΩ, or more, with 250 V DC megger between all supply terminals connected together and enclosure							
	Vibration r	resistance	10 to 500			G max.) in X, Y and Z directions for two hours each			
Shock resistance		500 m/s² acceleration (50 G approx.) in X, Y and Z directions for three times each							
Emitting element		Red LED (modulated)							
Material		Enclosure: Die-cast zinc (Nickel plated), Lens: Polycarbonate [EX-32 (-PN): Acrylic], Enclosure cover: Polycarbonate							
Cab	le			0.1 mm ² 3-core (thru-l	peam type sensor emi	tter: 2-core) cabtyre cable, 2 m 6			
	le le extensior	1	Extension up to to	0.1 mm ² 3-core (thru-botal 50 m 164.042 ft is	peam type sensor emis possible with 0.3 mm	tter: 2-core) cabtyre cable, 2 m 6 2, or more, cable (thru-beam type Net weight: 20 g approx., 0	e: both emitter and receiver).		

Notes: 1) Where measurement conditions have not been specified precisely, the conditions used were an ambient temperature of +23 °C +73.4 °F.

2) The sensing range and the hysteresis are specified for white non-glossy paper (100 \times 100 mm 3.937 \times 3.937 in) as the object.

3) Make sure to confirm detection with an actual sensor before use.

FIBER SENSORS

LASER SENSORS

> PHOTO-ELECTRIC SENSORS MICRO PHOTO-ELECTRIC

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